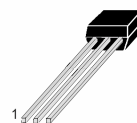


**APPLICATIONS**

Switching Circuit, Interface Circuit.

ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$) T_{stg} —Storage Temperature..... $-55\sim 150^{\circ}\text{C}$ T_j —Junction Temperature..... 150°C P_C —Collector Dissipation.....300mW V_{CBO} —Collector-Base Voltage.....50V V_{CEO} —Collector-Emitter Voltage.....50V V_{EBO} —Emitter-Base Voltage.....10V I_C —Collector Current.....100mA

TO-92S



1—Emitter, E

2—Collector, C

3—Base, B

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$)

Symbol	Characteristics	Min	Typ	Max	Unit	Test Conditions
BV_{CBO}	Collector-Base Breakdown Voltage	50			V	$I_C=10\mu\text{A}$, $I_E=0$
BV_{CEO}	Collector-Emitter Breakdown Voltage	50			V	$I_C=0.1\text{mA}$, $I_B=0$
BV_{EBO}	Emitter-Base Breakdown Voltage	5			V	$I_E=50\mu\text{A}$, $I_C=0$
I_{CBO}	Collector Cut-off Current			0.1	μA	$V_{\text{CB}}=40\text{V}$, $I_E=0$
I_{EBO}	Emitter Cut-off Current			0.1	μA	$V_{\text{EB}}=5\text{V}$, $I_C=0$
H_{FE}	DC Current Gain	100	250	600		$V_{\text{CE}}=5\text{V}$, $I_C=1\text{mA}$
$V_{\text{CE(sat)}}$	Collector- Emitter Saturation Voltage		0.1	0.3	V	$I_C=5\text{mA}$, $I_B=0.5\text{mA}$
$V_i(\text{off})$	Input Off Voltage	0.4	0.55	0.8	V	$V_{\text{CE}}=5\text{V}$, $I_C=0.1\text{mA}$
$V_i(\text{on})$	Input On Voltage	0.8	2.0	4.0	V	$V_{\text{CE}}=0.2\text{V}$, $I_C=5\text{mA}$
R1	Input Resistor	33	47	61	Kohm	
fr	Current Gain-Bandwidth Product		250		MHz	$V_{\text{CE}}=10\text{V}$, $I_C=5\text{mA}$
Cob	Output Capacitance		5.5		pF	$V_{\text{CB}}=10\text{V}$, $f=1\text{MHz}$